Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	92	("6218276" "6218276" "6037233" "6440807" "6803330" "6143608" "6245638" "5837612" "6376323" "6136728" "6063698" "6027961" "6069819" "5674788" "5397720" "5541436" "5436481" "6225169" "6225169" "6136654" "6225167" "4266985" "4913929" "4980307" "5418174" "5523596" "5589708" "5683929" "6245689" "6566281" "5963803" "6207995" "4785337" "4833094" "5705438" "4983544" "5488011" "5578516" "5923972" "5926728" "6080647" "6093945" "6187624" "6190976" "6211556" "6214662" "6211556" "6214662" "4873557" "5017982").pn.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:27
L3	220	TiN same gate dielectric	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:27
L4	20	TiN same gate dielectric and encapsulation	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:27
L5	89	TiN with gate dielectric	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:28
L6	412	gate electrode and encapsulation	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:28
L7	196	gate electrode and encapsulation and silicon nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:28
L8	2	silicon nitride encapsulation layer and gate electrode	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:28
L9	8	silicon nitride encapsulation layer and gate	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:28
L10	12	silicon nitride encapsulation layer	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/07/19 14:28

L11	7665	metal nitride or metal silicon nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2005/07/19 14:28
L12	2599	(metal nitride or metal silicon nitride) and gate	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:29
L13	1317	(metal nitride or metal silicon nitride) and gate and silicide	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:29
L14	20	(metal nitride or metal silicon nitride) and gate and silicide and encapsulation	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:29
L15	5	(metal nitride or metal silicon nitride) same gate and silicide and encapsulation	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:29
L16	33	("4628588"|"4641417"|"4672419"|"4954867"|"5633522"|"5723893"|"5937315"|"6218276"|"6265297"|"6274900"|"6376342"|"6383870"|"6410967"|"6432817"|"6602781"|"6617624").PN.	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:29
L17	811	257/314.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:30
L18	1661	257/314	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:30
L19	1183	L18 and nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/07/19 14:30
L20	1553	(257/315).CCLS.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:30
L21	1812	(257/316).CCLS.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:30
L22	1553	(257/315).CCLS.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:30

L23	963	L22 and nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:30
L24	963	L22 and nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/19 14:31
L25	67	L24 and nitride adj (spacer or sidewall)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 14:31